Features



## Low-Cost, Low-Voltage, Quad, SPST, CMOS Analog Switches

### General Description

The MAX4066/MAX4066A quad, SPST, CMOS analog switches are designed to provide superior performance over the industry-standard devices. These new switches feature guaranteed operation from +2.0V to +16V and are fully specified at 3V, 5V, and 12V. Both parts offer  $45\Omega$  on-resistance and  $2\Omega$  channel-to-channel matching at 12V, plus  $4\Omega$  flatness over the specified signal range.

Each device is controlled by TTL/CMOS input levels and can be used as a bilateral switch or multiplexer/demultiplexer.

Low off leakage current (100pA for the MAX4066A) and low power consumption (0.5µW) make the MAX4066/ MAX4066A ideal for battery-operated equipment. These parts are also suitable for low-distortion audio applications. Both devices are available in 14-pin DIP and SO packages, as well as a 16-pin QSOP. ESD protection is greater than 2000V per Method 3015.7.

### Applications

Battery-Operated Equipment
Audio and Video Signal Routing
Low-Voltage Data-Acquisition Systems
Sample-and-Hold Circuits
Communication Circuits

♦ Pin Compatible with 74HC4066

Guaranteed On-Resistance:
 170Ω max (3V supply)
 45Ω max (12V supply)

- Guaranteed Match Between Channels:
   4Ω max (MAX4066)
   2Ω max (MAX4066A)
- Guaranteed Low Leakage Currents:
   1nA at +25°C (MAX4066)
   100pA at +25°C (MAX4066A)
- ♦ Single-Supply Operation from +2.0V to +16V
- ♦ V+ to GND Signal Handling
- **♦ TTL/CMOS-Logic Compatible**
- ♦ Low Power Consumption: 0.5μW

Low Crosstalk: -86dB
Low Off Isolation: -58dB
Low Distortion: 0.03%
Wide Bandwidth: > 100MHz

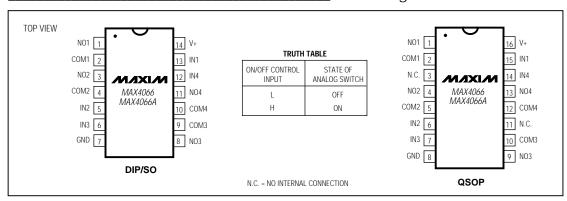
### \_Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX4066CPD	0°C to +70°C	14 Plastic DIP
MAX4066CSD	0°C to +70°C	14 Narrow SO
MAX4066CEE	0°C to +70°C	16 QSOP
MAX4066C/D	0°C to +70°C	Dice*

#### Ordering Information continued at end of data sheet.

\* Contact factory for dice specifications.

### Pin Configurations/Truth Table



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### **ABSOLUTE MAXIMUM RATINGS**

(Voltages referenced to GND)		
V+	0.3V to +17V	CERDIP (derate 9.09m\
VIN_, VCOM_, VNO (Note 1)0.3\	/ to (V + +0.3V)	Operating Temperature
Current (any terminal)	30mA	MAX4066C/MAX406
Peak Current (any terminal)	100mA	MAX4066E/MAX406
ESD per Method 3015.7	>2000V	MAX4066MJD/MAX406
Continuous Power Dissipation (T <sub>A</sub> = +70°C)		Storage Temperature Ra
Plastic DIP (derate 10.00mW/°C above +70°C)	800mW	Lead Temperature (sold
Narrow SO (derate 8.00mW/°C above +70°C)	640mW	
OSOP (derate 9.52mW/°C above +70°C)	762mW	

CERDIP (derate 9.09mW/°C above +70°	°C)727mW
Operating Temperature Ranges	
MAX4066C/MAX4066AC	0°C to +70°C
MAX4066E/MAX4066AE	40°C to +85°C
MAX4066MJD/MAX4066AMJD	55°C to +125°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10sec)	+300°C

**Note 1:** Signals on NO\_, COM\_, or IN\_ exceeding V+ or GND are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **ELECTRICAL CHARACTERISTICS—Single +12V Supply**

(V+ = 12V  $\pm$ 10%, GND = 0V, V<sub>INH</sub> = 4.0V, V<sub>INL</sub> = 0.8V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS	
ANALOG SWITCH								
Analog Signal Range	V <sub>COM</sub> , V <sub>NO</sub>	(Note 3)			0		V+	V
		V+ = 12V,	T <sub>A</sub> = +25°C	;		16	45	
On-Resistance	Ron	$I_{COM} = 2mA$ ,	TA = TMIN	C, E			55	Ω
		V <sub>NO</sub> = 10V	to T <sub>MAX</sub>	М			75	
On-Resistance Match		V + = 12V,	T <sub>A</sub> = +25°C	MAX4066		0.5	4	Ω
Between Channels (Note 4)	$\Delta R_{ON}$	ICOM = 2mA,	1A - 125 C	MAX4066A		0.5	2	
,		V <sub>NO</sub> = 10V	$T_A = T_{MIN} t$	о Т <sub>МАХ</sub>			6	
On-Resistance Flatness	RFLAT(ON)	V+ = 12V, I <sub>COM</sub> = 2mA, V <sub>NO</sub> = 10V, 5V, 1V	$T_A = +25^{\circ}C$	;		2	4	Ω
(Note 5)			TA = TMIN t	о Тмах			6	1 12
	INO(OFF)	V+ = 12V, VCOM = 0V, VNO = 10V	T <sub>A</sub> = +25°C	MAX4066	-1		1	nA
NO or NC Off Leakage			IA = +25 C	MAX4066A	-0.1		0.1	
Current (Note 6)			$T_A = T_{MIN}$	C, E	-6		6	IIA
			to T <sub>MAX</sub>	М	-100		100	]
		V+ = 12V,	T <sub>A</sub> = +25°C	MAX4066	-1		1	
COM Off Leakage Current	ICOM(OFF)		1A = +25 C	MAX4066A	-0.1		0.1	nA
(Note 6)	ICOM(OFF)	V <sub>COM</sub> = 0V, V <sub>NO</sub> = 10V	TA = TMIN	C, E	-6		6	
		.,,,	to T <sub>MAX</sub>	М	-100		100	
	ICOM(ON)		T <sub>A</sub> = +25°C	MAX4066	-2		2	
COM On Leakage Current (Note 6)		V + = 12V, $V_{COM} = 10V,$ $V_{NO} = 10V$	1A = +25 C	MAX4066A	-0.2		0.2	nA
			'A_ 'IVIIIV	C, E	-12		12	
		•		М	-200		200	

## **ELECTRICAL CHARACTERISTICS—Single +12V Supply (continued)** $(V+=12V\pm10\%, GND=0V, V_{INH}=4.0V, V_{INL}=0.8V, T_A=T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.})$

PARAMETER	SYMBOL	CONDITIONS			TYP (Note 2)	MAX	UNITS
LOGIC INPUT							I.
Input Current with Input Voltage High	linh	IN = 5.0V, all others = 0.8\	I	-0.5	0.005	0.5	μA
Input Current with Input Voltage Low	I <sub>INL</sub>	IN = 0.8V, all others = 5.0\	l	-0.5	0.005	0.5	μΑ
DYNAMIC							
Turn-On Time	ton	V <sub>COM</sub> = 10V, Figure 2	$T_A = +25^{\circ}C$ $T_A = T_{MIN} \text{ to } T_{MAX}$		25	100 150	ns
Turn-Off Time	toff	V <sub>COM</sub> = 10V, Figure 2	$T_A = +25^{\circ}C$ $T_A = T_{MIN} \text{ to } T_{MAX}$		15	75 100	ns
On-Channel Bandwidth	BW	Signal = 0dbm, Figure 4, $50\Omega$ in and out	T <sub>A</sub> = +25°C		100		MHz
Charge Injection (Note 3)	VCTE	$C_L = 1.0 nF$ , $V_{GEN} = 0V$ , $R_{GEN} = 0\Omega$ , Figure 3	T <sub>A</sub> = +25°C		1	10	рС
Off Isolation (Note 7)	VISO	$R_L = 50\Omega$ , $C_L = 5pF$ , $f = 1MHz$ , Figure 4	T <sub>A</sub> = +25°C		-58		dB
Crosstalk (Note 8)	V <sub>CT</sub>	$R_L = 50\Omega$ , $C_L = 5pF$ , $f = 1MHz$ , Figure 5	T <sub>A</sub> = +25°C		-86		dB
NO Capacitance	C(OFF)	f = 1MHz, Figure 6	T <sub>A</sub> = +25°C		9		рF
COM Off Capacitance	C <sub>COM(OFF)</sub>	f = 1MHz, Figure 6	$T_A = +25^{\circ}C$		9		pF
COM On Capacitance	CCOM(ON)	f = 1MHz, Figure 6	T <sub>A</sub> = +25°C		22		pF
SUPPLY							
Power-Supply Range							V
Supply Current	I+	V <sub>IN</sub> = 0V or V+, all channels on or off	TA = TMIN to TMAX	-1	0.001	1	μА
Total Harmonic Distortion	THD		$T_A = T_{MIN}$ to $T_{MAX}$		0.03		%

 $\begin{tabular}{lllll} \textbf{ELECTRICAL CHARACTERISTICS} & --Single +5V Supply \\ (V+=5V \pm 10\%, V-=0V \pm 10\%, GND=0V, V_{INH}=2.4V, V_{INL}=0.8V, T_A=T_{MIN} \ to \ T_{MAX}, \ unless \ otherwise \ noted.) \\ \end{tabular}$ 

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS	
ANALOG SWITCH								
Analog Signal Range	V <sub>COM</sub> , V <sub>NO</sub>	(Note 3)			0		V+	V
		V+ = 4.5V.	T <sub>A</sub> = +25°C	;		45	75	
On-Resistance	RON	$I_{COM} = -1.0 \text{mA},$	T <sub>A</sub> = T <sub>MIN</sub>	C, E		52	100	Ω
		$V_{NO} = 3.5V$	to T <sub>MAX</sub>	М			125	
On-Resistance Match	_	V+ = 5V,	T <sub>A</sub> = +25°C	;		0.3	4	
Between Channels (Note 4)	ΔR <sub>ON</sub>	$I_{COM} = -1.0 \text{mA},$ $V_{NO} = 3 \text{V}$	TA = TMIN t	о Тмах			12	Ω
On-Resistance Flatness	_	V+ = 5V,	T <sub>A</sub> = +25°C	;		4	6	_
(Notes 3, 5)	RFLAT(ON)	$I_{COM} = -1.0 \text{mA},$ $V_{NO} = 1 \text{V}, 3 \text{V}$	T <sub>A</sub> = T <sub>MIN</sub> t	о Т <sub>МАХ</sub>			8	Ω
		1110		MAX4066	-1		1	nA
NO Off Leakage Current (Note 6)	INO(OFF)	V+ = 5.5V, VCOM = 0V, V <sub>NO</sub> = 4.5V	$T_A = +25^{\circ}C$	MAX4066A	-0.1		0.1	
			TA = TMIN	C, E	-6		6	
			to T <sub>MAX</sub>	М	-100		100	
COM Off Leakage Current	ICOM(OFF)	V+ = 5.5V, VCOM = 0V, V <sub>NO</sub> = 4.5V	IT <sub>A</sub> = +25°C ⊢	MAX4066	-1		1	nA
				MAX4066A	-0.1		0.1	
(Note 6)			T <sub>A</sub> = T <sub>MIN</sub> C, E to T <sub>MAX</sub> M	C, E	-6		6	
				М	-100		100	
	ICOM(ON)	V+ = 5.5V, VCOM = 5V, VNO = 4.5V	$T_{\Lambda} = +25^{\circ}C$	MAX4066	-2		2	nA
COM On Leakage Current				MAX4066A	-0.2		0.2	
(Note 6)				C, E	-12		12	
				М	-200		200	
DYNAMIC								
Turn-On Time	ton	$V_{NO} = 3V$	T <sub>A</sub> = +25°C			43	125	ns
			TA = TMIN t				175	
Turn-Off Time	toff	V <sub>NO</sub> = 3V	T <sub>A</sub> = +25°C			18	75	ns
			T <sub>A</sub> = T <sub>MIN</sub> t	O IMAX			125	
On-Channel Bandwidth	BW	Signal = 0dBm, $50\Omega$ in and out, Figure 4	2 4			100		MHz
Charge Injection (Note 3)	Q	VGEN = 0V, RGEN = 0V, C <sub>L</sub> = 1.0nF, Figure 3	/, TA = +25°C			2	10	рС
SUPPLY	1		1					l
Positive Supply Current	I+	$V+ = 5.5V$ , $V_{IN} = 0V$ or $V+$ , all channels on or off			-1		1	μA

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### **ELECTRICAL CHARACTERISTICS—Single +3V Supply**

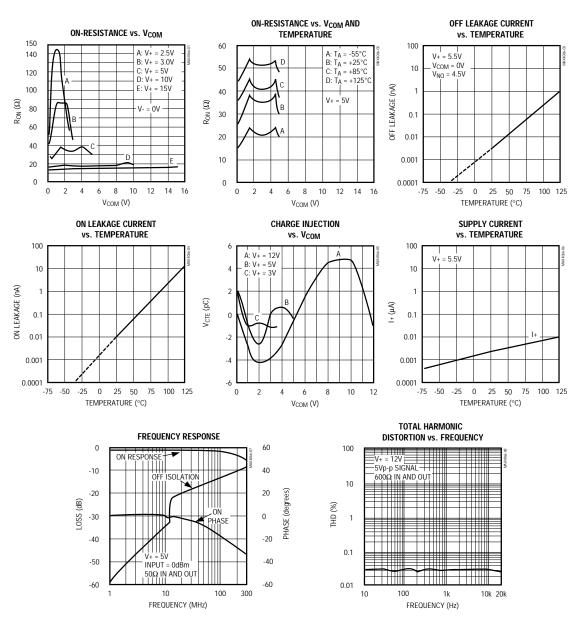
 $(V + = 2.7V \text{ to } 3.3V \pm 10\%, \text{ GND} = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.})$ 

PARAMETER	SYMBOL	CONDITIONS			TYP (Note 2)	MAX	UNITS
ANALOG SWITCH	•						
Analog Signal Range	V <sub>COM</sub> , V <sub>NO</sub>	(Note 3)		0		V+	V
Channel On-Resistance	Post	V+ = 3V,	T <sub>A</sub> = +25°C			170	Ω
Chariner On-Resistance	RON $I_{COM} = -1.0 \text{mA},$ $V_{NO} = 1.5 \text{V}$		TA = TMIN to TMAX			225	52
DYNAMIC	•						
Turn-On Time (Note 3)	ton	$V_{NO} = 3V,$ $V_{NO} \text{ or } V_{NC} = 1.5V$	T <sub>A</sub> = +25°C		80	185	ns
rum-on nine (Note 3)	ION		$T_A = T_{MIN}$ to $T_{MAX}$			230	113
Turn-Off Time (Note 3)	toff	V+ = 3V,	$T_A = +25^{\circ}C$		28	150	ns
rum-on time (Note 3)	TOFF	V <sub>NO</sub> or V <sub>NC</sub> = 1.5V	TA = TMIN to TMAX			200	115
Charge Injection (Note 3)	Q	$C_L = 1.0nF$ , $V_{GEN} = 0V$ , $R_{GEN} = 0V$ $T_A = +25$ °C			2	10	рС
SUPPLY	•	•					•
Positive Supply Current	I+	V+ = 3.6V, V <sub>IN</sub> = 0V or V+, all channels on or off		-1	0.001	1	μA

- Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.
- Note 3: Guaranteed by design.
- Note 4:  $\Delta R_{ON} = R_{ON} \text{ (max)} R_{ON} \text{ (min)}.$
- **Note 5:** Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal range.
- Note 6: Leakage parameters are 100% tested at maximum-rated hot temperature and guaranteed by correlation at +25°C.
- **Note 7:** Off Isolation =  $20\log_{10}$  (V<sub>COM</sub> / V<sub>NO</sub>), V<sub>COM</sub> = output, V<sub>NO</sub> = input to off switch.
- Note 8: Between any two switches.

\_Typical Operating Characteristics

 $(T_A = +25^{\circ}C, unless otherwise noted.)$ 



Pin Description

Р	IN	NAME	FUNCTION	
DIP/SO	QSOP	NAME	FUNCTION	
1, 3, 8, 11	1, 4, 9, 13	NO1-NO4	Analog Switch Normally Open Terminal (bidirectional)	
2, 4, 9, 10	2, 5, 10, 12	COM1-COM4	Analog Switch Common Terminal (bidirectional)	
_	3, 11	N.C.	Not internally connected	
13, 5, 6, 12	15, 6, 7, 14	IN1-IN4	Logic Control Inputs	
7	8	GND	Ground	
14	16	V+	Positive Supply Voltage	

### \_Applications Information

### Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings may cause permanent damage to the devices. Always sequence V+ on first, followed by the logic inputs. If power-supply sequencing is not possible, add two small signal diodes in series with supply pins for overvoltage protection (Figure 1). Adding diodes reduces the analog signal range to 1V below V+ and IV above GND, but low switch resistance and low leakage characteristics are unaffected. Device operation is unchanged, and the difference between V+ and GND should not exceed 17V.

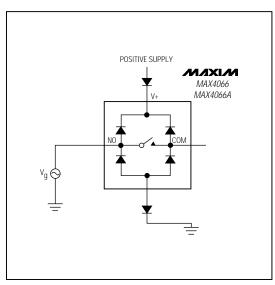


Figure 1. Overvoltage Protection Using Two External Blocking Diodes

\_Test Circuits/Timing Diagrams

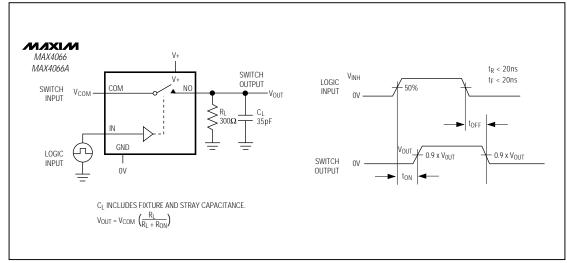


Figure 2. Switching Time

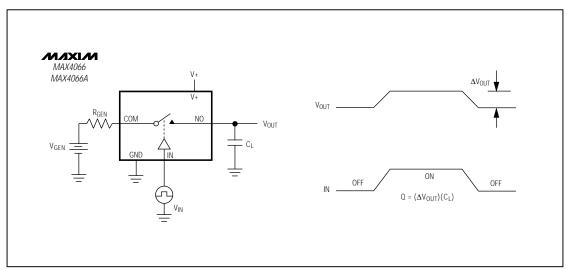


Figure 3. Charge Injection

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\_Test Circuits (continued)

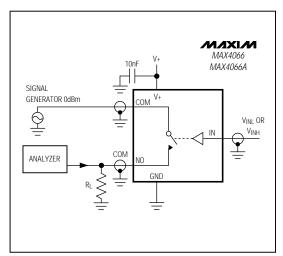


Figure 4. Off Isolation/On-Channel Bandwidth

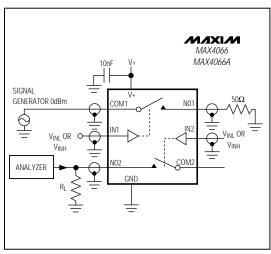


Figure 5. Crosstalk

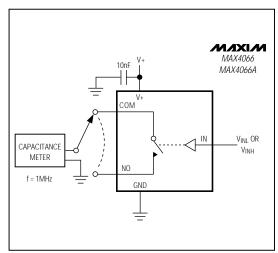
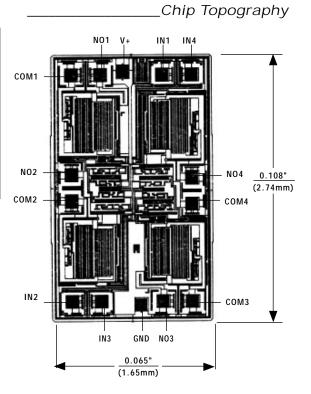


Figure 6. Channel Off/On Capacitance

### \_Ordering Information (continued)

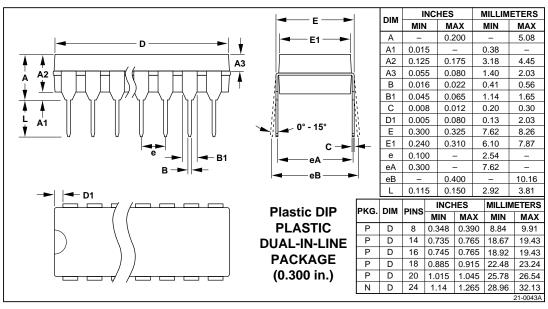
PART	TEMP. RANGE	PIN-PACKAGE
MAX4066EPD	-40°C to +85°C	14 Plastic DIP
MAX4066ESD	-40°C to +85°C	14 Narrow SO
MAX4066MJD	-55°C to +125°C	14 CERDIP**
MAX4066ACPD	0°C to +70°C	14 Plastic DIP
MAX4066ACSD	0°C to +70°C	14 Narrow SO
MAX4066ACEE	0°C to +70°C	16 QSOP
MAX4066AC/D	0°C to +70°C	Dice*
MAX4066AEPD	-40°C to +85°C	14 Plastic DIP
MAX4066AESD	-40°C to +85°C	14 Narrow SO
MAX4066AEEE	-40°C to +85°C	16 QSOP
MAX4066AMJD	-55°C to +125°C	14 CERDIP**

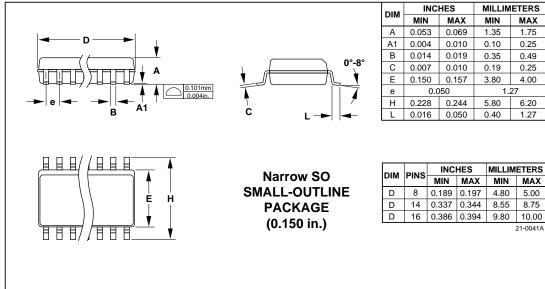
<sup>\*</sup> Contact factory for dice specifications. \*\* Contact factory for availability.



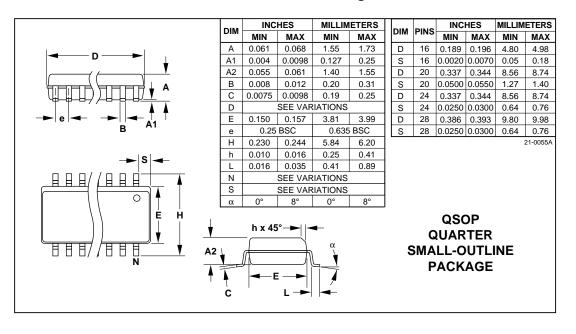
TRANSISTOR COUNT: 69 SUBSTRATE CONNECTED TO V+

\_Package Information





Package Information (continued)



Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.